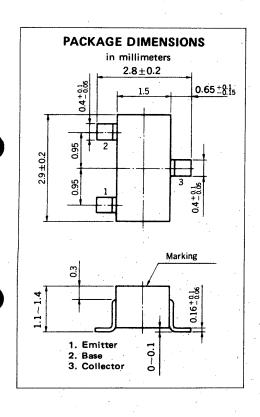


SILICON TRANSISTOR 2SD596

AUDIO FREQUENCY POWER AMPLIFIER NPN SILICON EPITAXIAL TRANSISTOR MINI MOLD



DESCRIPTION

The 2SD596 is designed for use in small type equipments especially recommended for hybrid integrated circuit and other applications.

FEATURES

- Micro package.
- High DC current gain. h_{FE}: 200 TYP. (V_{CE} = 1.0 V, I_C = 100 mA)
- Complimentary to NEC 2SB624 PNP Transistor.

ABSOLUTE MAXIMUM RATINGS

Maximum Voltages and Current (T_A = 25 °C)

Collector to Base Voltage	V _{CBO}	30	V
Collector to Emitter Voltage	V _{CEO}	25	V
Emitter to Base Voltage	V_{EBO}	5.0	V
Collector Current (DC)	lc .	700	mΑ
Maximum Power Dissipation			•
Total Power Dissipation		•	
at 25 °C Ambient Temperature	PT	200	mW
Maximum Temperatures			
Storage Temperature Range	T _{stg}	- 55 to +150	°C

imum Temperatures			
Storage Temperature Range	T _{stg}	-55 to +150	°C
Operating Junction Temperature	Tj	150	°C

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

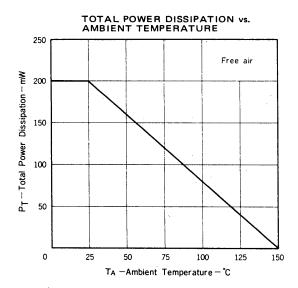
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Collector Cutoff Current	ІСВО			100	nA	V _{CB} = 30 V, I _E = 0
Emitter Cutoff Current	^I EBO			100	nA	V _{EB} = 5.0 V, I _C = 0
DC Current Gain	hFE1	110	200	400		V _{CE} = 1.0 V, I _C = 100 mA *
DC Current Gain	,hFE2	50				V _{CE} = 1.0 V, I _C = 700 mA *
Base to Emitter Voltage	V _{BE}	600	640	700	mV .	V _{CE} = 6.0 V, I _C = 10 mA *
Collector Saturation Voltage	VCE(sat)		0.22	0.6	٧	I _C = 700 mA, I _B = 70 mA *
Output Capacitance	C _{ob}		12	4 5	рF	V _{CB} = 6.0 V, I _E = 0, f = 10 MHz
Gain Bandwidth Product	fT		170		MHz	V _{CE} = 6.0 V, I _E = -10 mA

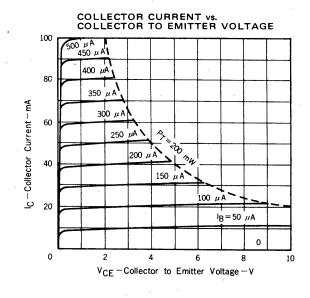
^{*} Pulsed: PW \leq 350 μ s, Duty Cycle \leq 2 %

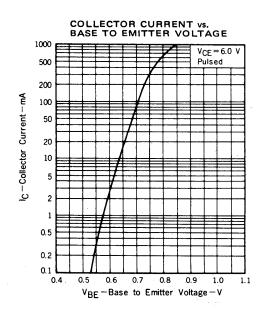
hFE1 Classification

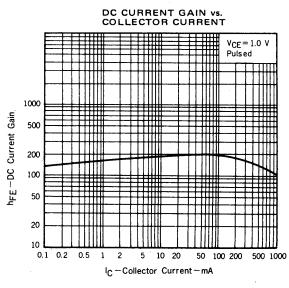
Marking	DV1	DV2	DV3	DV4	DV5
hFE	110 to 180	135 to 220	.170 to 270.	200 to 320	250 to 400

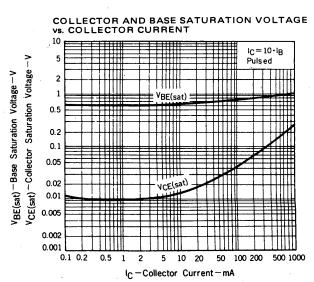
TYPICAL CHARACTERISTICS (TA = 25 °C)

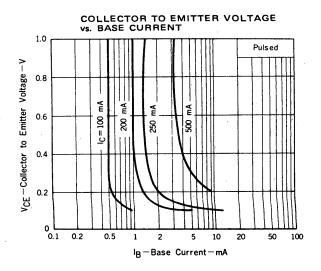


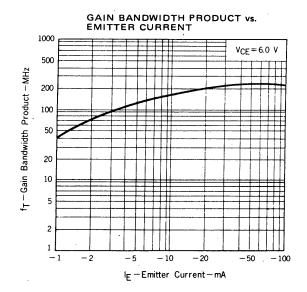


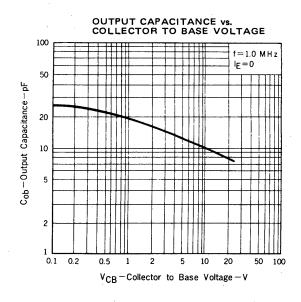












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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.

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